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08/937,721 APPLICATION NO. 09/25/97

FILING DATE

WIII. B 13 14. . . .

FIRST NAMED INVENTOR

ATTORNEY DOCKET NO.

MM31/1015

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ART UNIT	PAPER NUMBER		

DATE MAILED:

Please find below and/or attached an Office communication concerning this application or proceeding.

**Commissioner of Patents and Trademarks** 

	Application No.	Applicant(s)		
Office Action Summers	08/937	721 GE	SSERT	
Office Action Summary	Examiner S-M	ULPURI	Group Art Unit	
—The MAILING DATE of this communication appe	ears on the cover si	neet beneath the c	orrespondence address—	
Period for Response				
A SHORTENED STATUTORY PERIOD FOR RESPONSE IS MAILING DATE OF THIS COMMUNICATION.	SET TO EXPIRE_	3MONT	TH(S) FROM THE	
<ul> <li>Extensions of time may be available under the provisions of 37 CFF from the mailing date of this communication.</li> <li>If the period for response specified above is less than thirty (30) day</li> <li>If NO period for response is specified above, such period shall, by one of the period of the period</li></ul>	ys, a response within the default, expire SIX (6) Mo	statutory minimum of to	thirty (30) days will be considered timely.	
Status			(1000000)	
☐ Responsive to communication(s) filed on	25/97	_		
☐ This action is FINAL.	7		,	
☐ Since this application is in condition for allowance exce accordance with the practice under <i>Ex parte Quayle</i> , 19	pt for formal matters, 335 C.D. 1 1; 453 O.	prosecution as to G. 213.	the merits is closed in	
Disposition of Claims				
© Claim(s) 6		is/are	is/are pending in the application.	
Of the above claim(s)				
☐ Claim(s)		is/are	is/are allowed	
Defaim(s) (-6			is/are rejected.	
□ Claim(s)			is/are objected to.	
□ Claim(s)		are su		
Application Papers			ement.	
See the attached Notice of Draftsperson's Patent Draw	ing Review PTO-941	a		
☐ The proposed drawing correction, filed on			nd	
☐ The drawing(s) filed on is/are objection		• • •		
☐ The specification is objected to by the Examiner.	•		•	
$\hfill\Box$ The oath or declaration is objected to by the Examiner.				
Priority under 35 U.S.C. § 119 (a)-(d)				
<ul> <li>□ Acknowledgment is made of a claim for foreign priority</li> <li>□ All □ Some* □ None of the CERTIFIED copies of received.</li> </ul>				
<ul> <li>□ received in Application No. (Series Code/Serial Num</li> <li>□ received in this national stage application from the In</li> </ul>				
*Certified copies not received:			··	
Attachment(s)				
Unformation Disclosure Statement(s), PTO-1449, Paper	No(s). 2 .	☐ Interview Sum	mary, PTO-413	
☐ Notice of References Cited, PTO-892 ☐ Notice of Draftsperson's Patent Drawing Review, PTO-948		☐ Notice of Informal Patent Application, PTO-152 ☐ Other		

U. S. Patent and Trademark Office PTO-326 (Rev. 3-97)

\*U.S. GPO: 1997-417-381/62710

Office Action Summary

Part of Paper No.\_\_\_\_\_

Application/Control Number: 08/937721

Art Unit: 2812

## **DETAILED ACTION**

1.Claim 5 is rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

It is not understood what is meant by aperture of about 3 cm. Is it aperture diameter or radius or length or width. Clarification is requested.

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 1-4 are rejected under 35 U.S.C. 103(a) as being unpatentable over Admitted Prior Art in combination with Schroen et al..

Admitted Prior Art discloses a method of making CDS/CdTe device. But does not discloses exposing the p-type CdTe to the Ar ions or atoms to reduce contact resistance. Schroen et al discloses evacuating residual gas to pressure of 5 X 10<sup>-7</sup> Torr, providing Ar gas and creating Ar ion beam using glow discharge at 1000 volts and then exposing Ar ions to the doped semiconductor substrate and then forming ohmic contact. It would have been obvious to one of ordinary skill in the art to expose Ar ions to surface of CdTe to obtain low ohmic contact

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resistance. The mean free path in the invention of Schroen et al would have been same as claimed mean free path because the experimental conditions in Schroen et al are substantially same as instantly claimed conditions.

Claim 5 is rejected under 35 U.S.C. 103(a) as being unpatentable over Admitted Prior Art in combination with Schroen et al as applied to claims 1-4 above, and further in view of Lee et al..

Neither admitted Prior Art nor Schroen et al disclose an aperture dimension. Lee et al disclose an aperture diameter of Ar plasma is 3 cm(see col.3, lines 35-63). It would have been obvious to one of ordinary skill in the art to use chamber having large aperture of 3 cm in the invention of Schroen et al.

because aperture size suitable for the ion etching ion cleaning on the surface of the substrate.

Claim 6 is rejected under 35 U.S.C. 103(a) as being unpatentable over Admitted Prior Art in combination with Schroen et al. as applied to claim s 1-4 above, and further in view of Ebe et al.

Neither Admitted Prior art nor Schroen et al disclose using angle implantation. Ebe et al disclose using exposing Ar ions at an angle of 45 degrees to substrate(see fig.4, col. 5, 60-67). It would have been obvious to one of ordinary skill in the art to use angle implantation in the invention of Schroen et al because Ebe et al teaches angle implantation is suitable for finally making integrated circuits.

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The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Morita disclose angle implantation of Ar ions. Wotherspoon teaches etching of CdTe layer.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to S. Mulpuri whose telephone number is (703) 305-5184. The fax phone number for the organization where this application or proceeding is assigned is (703) 305-3432.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 305-4900.

S. M

10/12/98

S. Mulpuri

Patent examiner

Technology center 2800